

DUAL HIGH PERFORMANCE OPERATIONAL AMPLIFIER

SE/NE5512

DESCRIPTION

The 5512 series of high performance operational amplifier provides very good input characteristics. These amplifiers feature low input bias and voltage characteristics such as a 108 op amp with improved CMRR and a high differential input voltage limit achieved through the use of a bias cancellation and PNP input circuits with collector to emitter clamping. The output characteristics are like those of a 741 op amp with improved slew rate and drive capability yet have low supply quiescent current.

APPLICATIONS

- AC amplifiers
- RC active filters
- Transducer amplifiers
- DC gain block
- Battery operation
- Instrumentation amplifiers

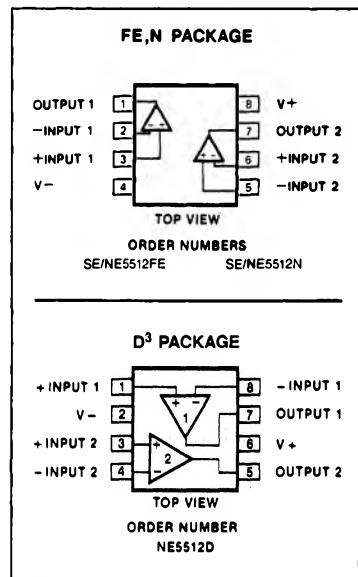
ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Unit
V _{CC}	Supply Voltage	± 16
V _D	Power dissipation	500
T _A	Operating temperature range	
NE5512	0 to 70	°C
SE5512	-55 to +125	°C
T _{STG}	Storage temperature range	-65 to +150
T _{SOLD}	Lead temperature soldering	300

FEATURES

- Low input bias < ± 20nA
- Low input offset current < ± 20nA
- Low Input offset voltage < 1mV
- Low V_{os} temperature drift 5 μ V/°C
- Low Input bias temperature drift 40pA/°C
- Low input voltage noise 30nV/ $\sqrt{\text{Hz}}$
- Low supply current 1.5mA/amp
- High slew rate 1.0V/ μ s
- High CMRR 100dB
- High input impedance 100M Ω
- High PSRR 110dB
- High differential input voltage limit
- No cross-over distortion
- Indefinite output short circuit protection
- Internally compensated for unity gain
- 600 Ω drive capability

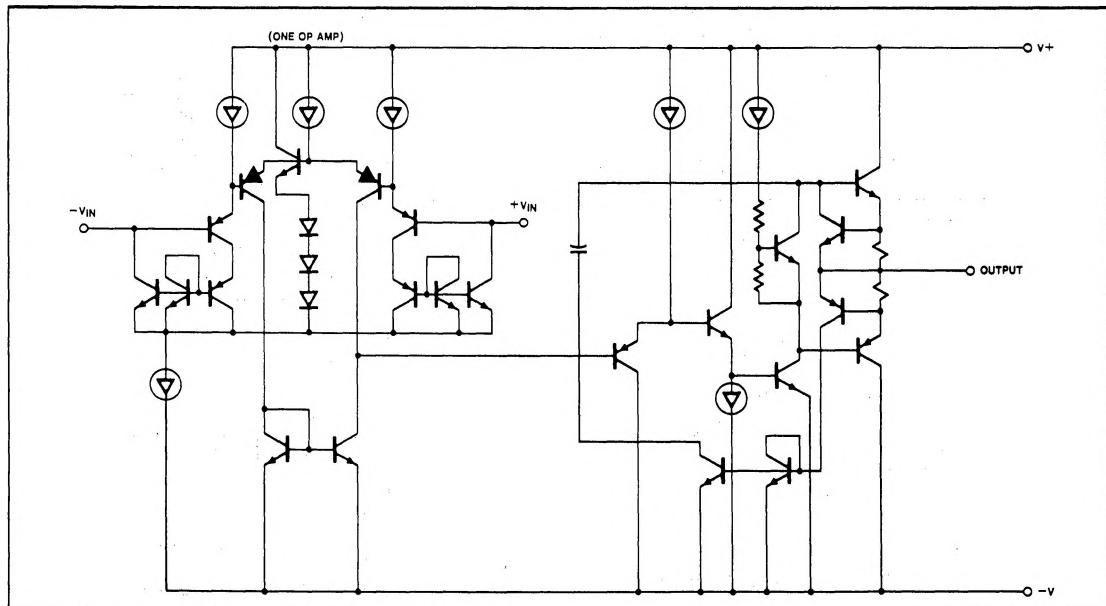
PIN CONFIGURATIONS



NOTES:

1. SOL - Released in large SO package only.
2. SOL and non-standard pinout.
3. SO and non-standard pinouts.

EQUIVALENT SCHEMATIC



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ELECTRICAL PERFORMANCE CHARACTERISTICS $V_{CC} = \pm 15V$, F.R. = -55°C to $+125^{\circ}\text{C}$ (SE), 0°C to $+70^{\circ}\text{C}$ (NE)

	PARAMETER	TEST CONDITIONS	SE5512			NE5512			UNIT
			Min	Typ	Max	Min	Typ	Max	
V_{OS}	Input offset voltage	$R_S = 100\Omega$ $T_A = +25^{\circ}\text{C}$ $T_A = \text{F.R.}$ Over Temp.		0.7 1 4	2 3		1 1.5 5	5 6	mV $\mu\text{V}/^{\circ}\text{C}$
ΔV_{OS}	Input offset current	$R_S = 100k\Omega$ $T_A = +25^{\circ}\text{C}$ $T_A = \text{F.R.}$ Over Temp.		3 4 30	10 20		6 8 40	20 30	nA $\text{pA}/^{\circ}\text{C}$
I_B	Input bias current	$R_S = 100k\Omega$ $T = +25^{\circ}\text{C}$ $T_A = \text{F.R.}$ Over Temp.		3 4 30	10 20		6 8 40	20 30	nA $\text{pA}/^{\circ}\text{C}$
ΔI_B									
R_{IN}	Input resistance differential	$T_A = 25^{\circ}\text{C}$		100			100		MΩ
V_{CM}	Input common mode range	$T_A = 25^{\circ}\text{C}$ $T_A = \text{F.R.}$	± 13.5 ± 13	± 13.7 ± 13.2		± 13.5 ± 13	± 13.7 ± 13.2		V
CMRR	Input common-mode rejection ratio	$V_{CC} = \pm 15V$ $V_{IN} = \pm 13.5V$ (RM) $T_A = 25^{\circ}\text{C}$ $V_{IN} = \pm 13V$ (F.R.) $T_A = \text{F.R.}$	70	100		70	100		dB
A_{VOL} GAIN	Large-signal voltage gain	$R_L = 2k\Omega$ $T_A = 25^{\circ}\text{C}$ $V_O = \pm 10V$ $T_A = \text{F.R.}$	50 25	200		50 25	200		V/mV
S.R.	Slew rate	$T_A = 25^{\circ}\text{C}$	0.6	1			1		V/ μs
GBW	Small-signal unity gain bandwidth	$T_A = 25^{\circ}\text{C}$		3			3		MHz
θ_M	Phase margin	$T_A = 25^{\circ}\text{C}$		45			45		Degree
V_{OUT}	Output voltage swing	$R_L = 2k\Omega$ $T_A = 25^{\circ}\text{C}$ $T_A = \text{F.R.}$	± 13 ± 12.5	± 13.5 ± 13		± 13 ± 12.5	± 13.5 ± 13		V
V_{OUT}	Output voltage swing	$R_L = 600\Omega$ $T_A = 25^{\circ}\text{C}$ $T_A = \text{F.R.}$	± 10 ± 7.5	± 11.5 ± 9		± 10 ± 8	± 11.5 ± 9		V
I_{CC}	Power supply current	$R_L = \text{Open}$ $T_A = 25^{\circ}\text{C}$ $T_A = \text{F.R.}$		3.4 3.6	5 5.5		3.4 3.6	5 5.5	mA
PSRR	Power supply rejection ratio	$T_A = 25^{\circ}\text{C}$ $T_A = \text{F.R.}$	80 80	110 100		80 80	110 100		dB
AA	Amplifier to amplifier coupling	$f = 1\text{kHz}$ to 20kHz $T_A = 25^{\circ}\text{C}$		-120			-120		dB
HD	Total harmonic distortion	$f = 10\text{kHz}$ $T_A = 25^{\circ}\text{C}$ $V_O = 7V_{\text{RMS}}$		0.01			0.01		%
V_{INN}	Input noise voltage	$f = 1\text{kHz}$ $T_A = 25^{\circ}\text{C}$		30			30		$\text{nV}/\sqrt{\text{Hz}}$
I_{INN}	Input noise current	$f = 1\text{kHz}$ $T_A = 25^{\circ}\text{C}$.2			.2		$\text{pA}/\sqrt{\text{Hz}}$
I_{SC}	Short circuit	$\pm 15V$ $T_A = 25^{\circ}\text{C}$		40			40		mA

NOTE

For operation at elevated temperature, N package must be derated based on a thermal resistance of $120^{\circ}\text{C}/\text{W}$ junction to ambient. Thermal resistance of the FE package is $125^{\circ}\text{C}/\text{W}$.

*For additional information, consult the Applications Section.